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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	D
2	D	drain	$2 \sim 10$	
3	S	source		G
mb	D	mounting base; connected to drain		mbb076 S
			TO-220AB (SOT78)	

6. Ordering information

Table 3. Ordering information								
Type number	Package							
	Name	Description	Version					
PSMN3R9-60PS	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78					

7. Marking

Table 4. Marking codes	
Type number	Marking code
PSMN3R9-60PS	PSMN3R9-60PS

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	60	V
V _{DGR}	drain-gate voltage	R _{GS} = 20 kΩ		-	60	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	T _{mb} = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u>	[1]	-	130	А
		T _{mb} = 100 °C; V _{GS} = 10 V; <u>Fig. 1</u>		-	127	А
I _{DM}	peak drain current	T_{mb} = 25 °C; pulsed; $t_p \le 10 \ \mu s$; Fig. 4		-	705	А

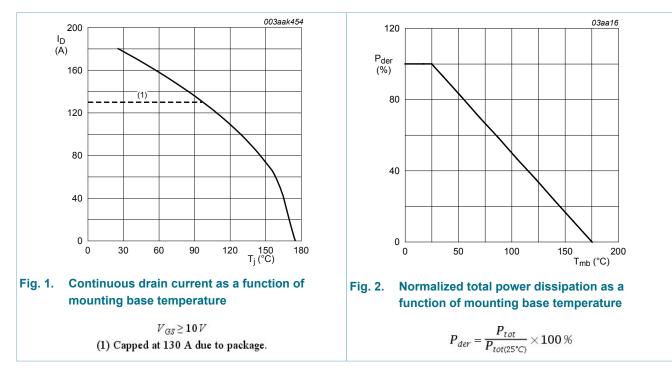
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Symbol	Parameter	Conditions		Min	Max	Unit
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	263	W
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drain	n diode					
I _S	source current	T _{mb} = 25 °C	[1]	-	130	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	705	А
Avalanche r	uggedness					
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$\begin{split} I_D &= 130 \text{ A}; V_{sup} \leq 60 \text{V}; \text{R}_{GS} = 50 \Omega; \\ $		-	283	mJ

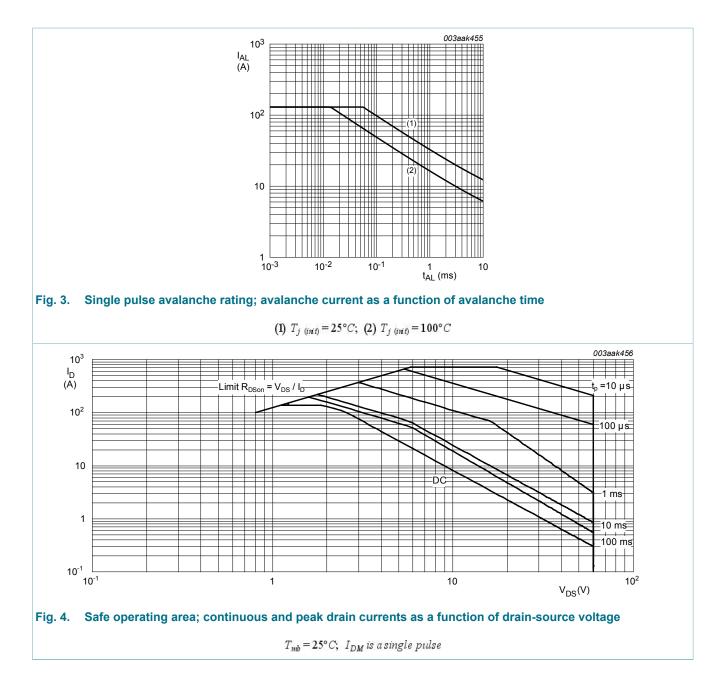


[1] Continuous current is limited by package.

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9. Thermal characteristics

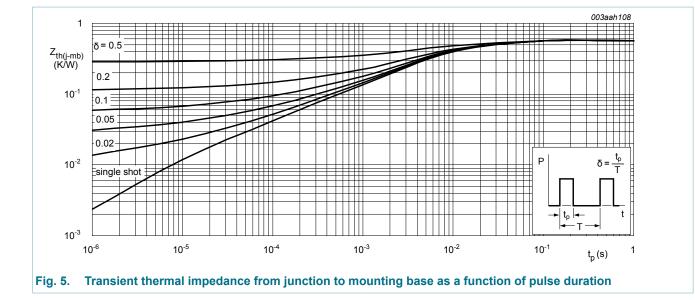
	-	• · · · ·		_		
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	0.49	0.57	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	vertical in still air	-	60	-	K/W

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10. Characteristics

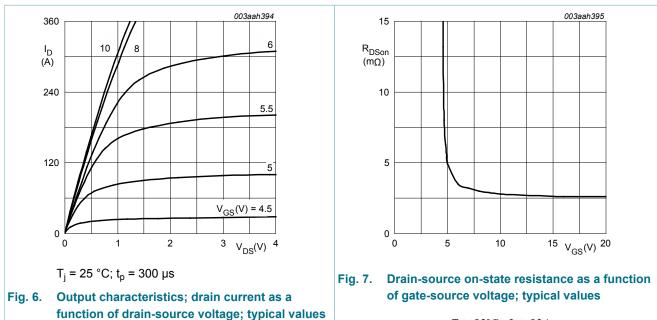
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · · ·				
V _{(BR)DSS}	drain-source	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	60	-	-	V
	breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = -55 °C	54	-	-	V
V _{GS(th)} gate-so voltage	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C};$ Fig. 9; Fig. 10	2.4	3	4	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ Fig. 9	1	-	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ Fig. 9	-	-	4.5	V
I _{DSS} d	drain leakage current	V_{DS} = 60 V; V_{GS} = 0 V; T_j = 175 °C	-	-	500	μA
		V_{DS} = 60 V; V_{GS} = 0 V; T_j = 25 °C	-	0.07	1	μA
I _{GSS}	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 11	-	2.94	3.9	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 11; Fig. 12	-	-	8.5	mΩ
R _G	gate resistance	f = 1 MHz	0.35	0.7	1.4	Ω
Dynamic cł	naracteristics		1			
Q _{G(tot)}	total gate charge	I_D = 25 A; V_{DS} = 48 V; V_{GS} = 10 V;	-	103	-	nC
Q _{GS}	gate-source charge	Fig. 13; Fig. 14	-	25.1	-	nC

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Q _{GD}	gate-drain charge			-	33	-	nC
C _{iss}	input capacitance	V _{GS} = 0 V; V _{DS} = 25 V; f = 1 MHz; T _j = 25 °C; <u>Fig. 15</u>		-	5600	-	pF
C _{oss}	output capacitance			-	740	-	pF
C _{rss}	reverse transfer capacitance			-	460	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 45 V; R_L = 1.8 Ω ; V_{GS} = 10 V; $R_{G(ext)}$ = 5 Ω		-	25.3	-	ns
t _r	rise time			-	41.4	-	ns
t _{d(off)}	turn-off delay time			-	62.7	-	ns
t _f	fall time			-	45	-	ns
Source-dra	ain diode	-	II				
V _{SD}	source-drain voltage	I_{S} = 25 A; V_{GS} = 0 V; T_{j} = 25 °C; <u>Fig. 16</u>		-	0.8	1.2	V
t _{rr}	reverse recovery time	I_{S} = 20 A; dI_{S}/dt = -100 A/µs; V _{GS} = 0 V;		-	39	-	ns
Qr	recovered charge	V _{DS} = 25 V		-	51	-	nC

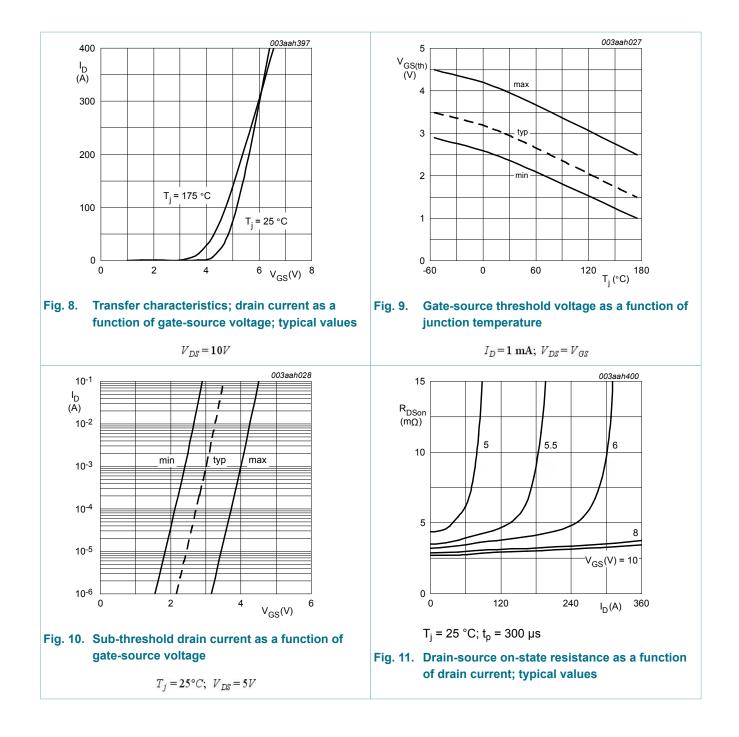


 $T_j = 25^{\circ}C; \ I_D = 25A$

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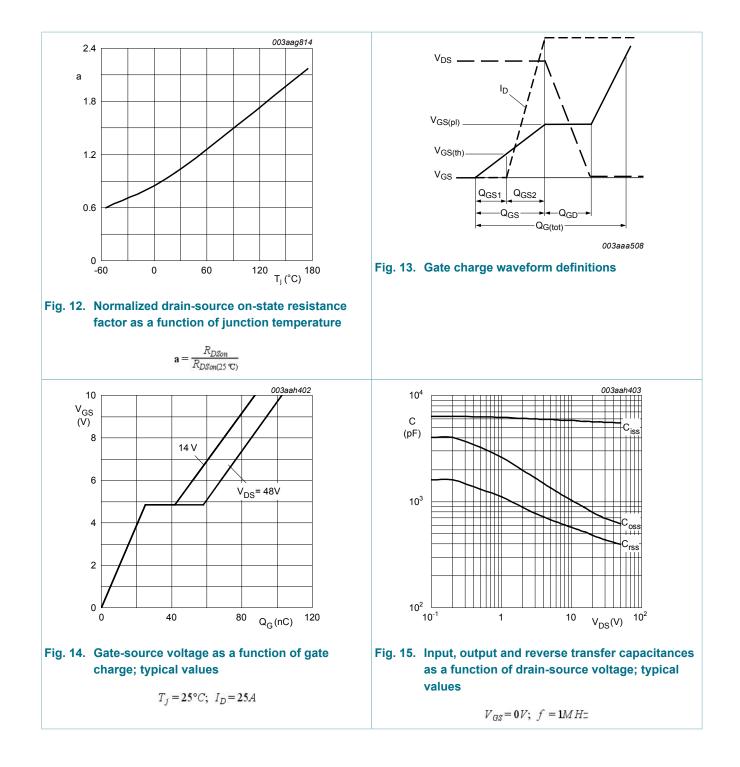
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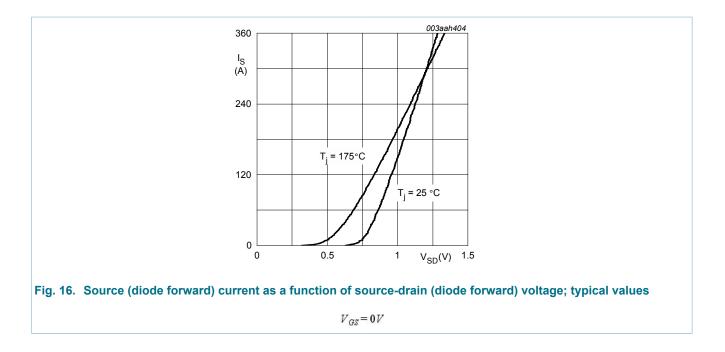
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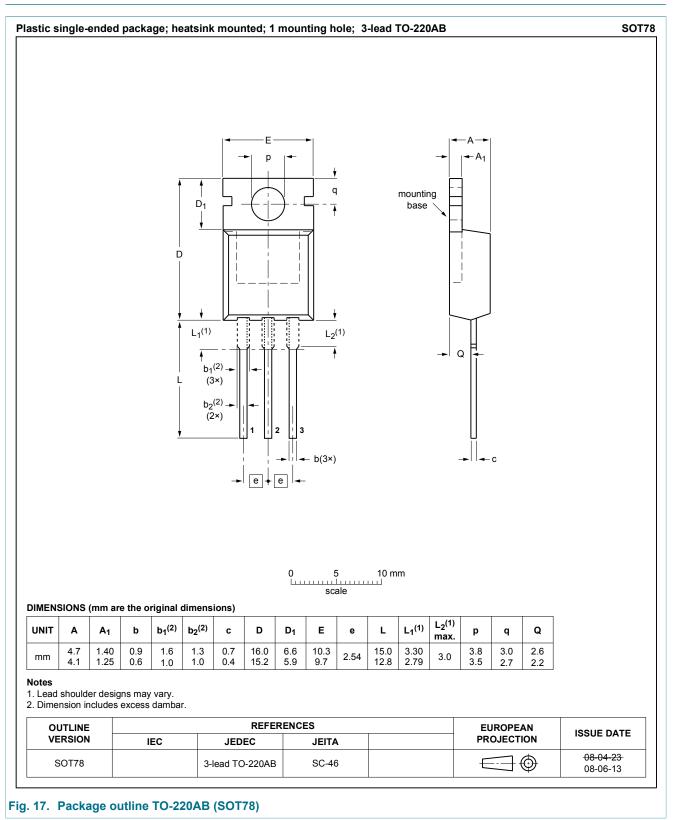
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11. Package outline



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12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or [1] completing a design.

The term 'short data sheet' is explained in section "Definitions". [2]

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